



MX23C1622

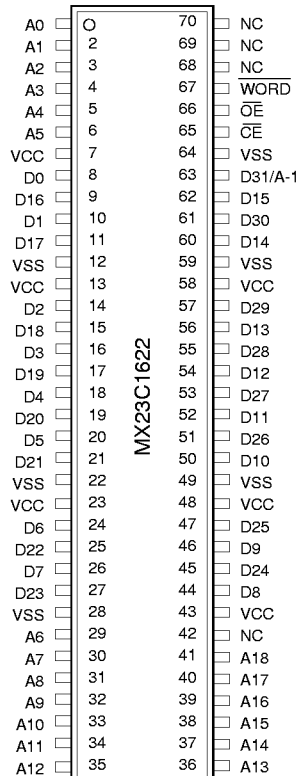
16M-BIT MASK ROM (16/32 BIT OUTPUT)

FEATURES

- Bit organization
 - 1M x 16 (word mode)
 - 512K x 32 (double word mode)
- Fast access time
 - Random access: 100ns (max.)
 - Page access: 30ns (max.)
- Page Size
 - 8 double words per page
- Current
 - Operating: 100mA
 - Standby: 50uA
- Supply voltage
 - 5V±10%
- Package
 - 70 pin SSOP (500 mil)

PIN CONFIGURATION

70 SSOP



ORDER INFORMATION

Part No.	Access Time	Page Access Time	Package
MX23C1622MC-10	100ns	30ns	70 pin SSOP
MX23C1622MC-12	120ns	50ns	70 pin SSOP

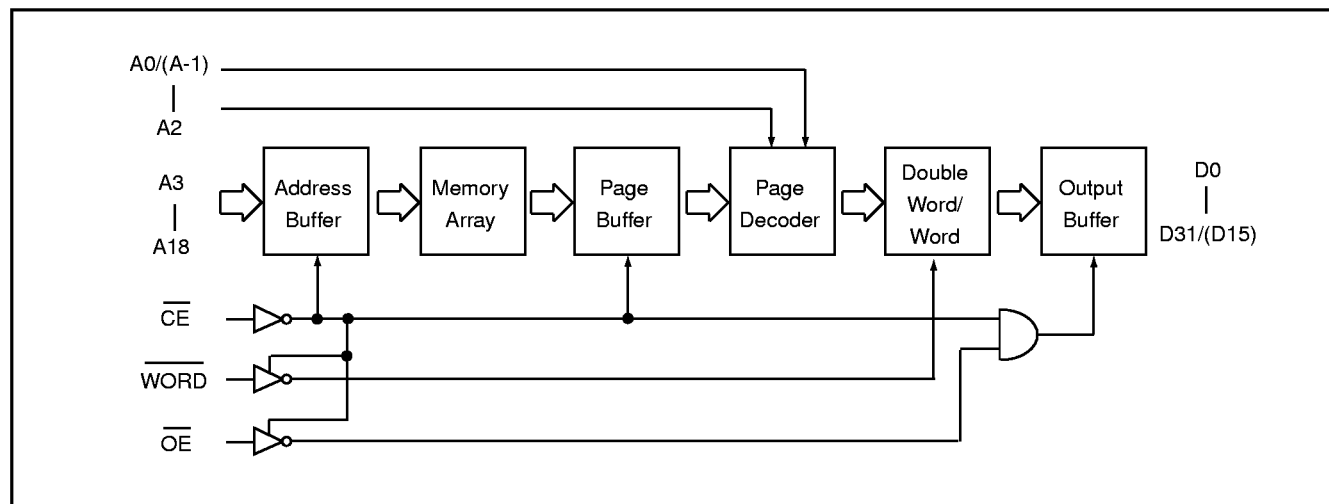
PIN DESCRIPTION

Symbol	Pin Function
A0~A18	Address Inputs
D0~D30	Data Outputs
D31/A-1	D31 (Double Word Mode)/ LSB Address (Word Mode)
CE	Chip Enable Input
OE	Output Enable Input
Word	Double Word/ Word Mode Selection
VCC	Power Supply Pin
VSS	Ground Pin
NC	No Connection

MODE SELECTION

CE	OE	Word	D31/A-1	D0~D15	D16~D31	Mode	Power
H	X	X	X	High Z	High Z	-	Stand-by
L	H	X	X	High Z	High Z	-	Active
L	L	H	Output	D0~D15	D16~D31	Double Word	Active
L	L	L	Input	D0~D15	High Z	Word	Active

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Ratings
Voltage on any Pin Relative to VSS	VIN	-1.3V to VCC+2.0V(Note)
Ambient Operating Temperature	T _{opr}	0°C to 70°C
Storage Temperature	T _{stg}	-65°C to 125°C

Note: Minimum DC voltage on input or I/O pins is -0.5V. During voltage transitions, inputs may undershoot VSS to -1.3V for periods of up to 20ns. Maximum DC voltage on input or I/O pins is VCC+0.5V. During voltage transitions, input may overshoot VCC to VCC+2.0V for periods of up to 20ns.

DC CHARACTERISTICS (T_a = 0°C ~ 70°C, VCC = 5V±10%)

Item	Symbol	MIN.	MAX.	Conditions
Output High Voltage	VOH	2.4V	-	I _{OH} = -1.0mA
Output Low Voltage	VOL	-	0.4V	I _{OL} = 2.1mA
Input High Voltage	VIH	2.2V	VCC+0.3V	
Input Low Voltage	VIL	-0.3V	0.8V	
Input Leakage Current	ILI	-	5uA	0V, VCC
Output Leakage Current	ILO	-	5uA	0V, VCC
Operating Current	ICC1	-	100mA	t _{RC} = 100ns, all output open
Standby Current (TTL)	ISTB1	-	1mA	$\overline{CE}$ = VIH
Standby Current (CMOS)	ISTB2	-	50uA	$\overline{CE}$ > VCC-0.2V
Input Capacitance	CIN	-	10pF	T _a = 25°C, f = 1MHZ
Output Capacitance	COUT	-	10pF	T _a = 25°C, f = 1MHZ

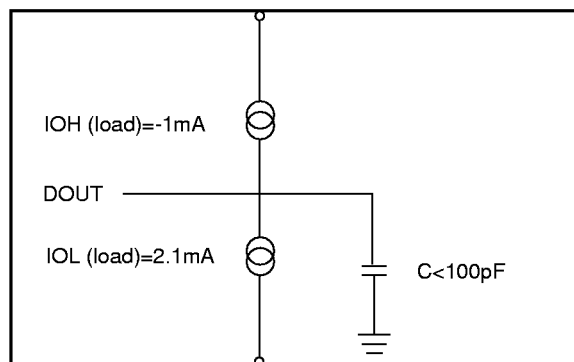
AC CHARACTERISTICS ($T_a = 0^{\circ}\text{C} \sim 70^{\circ}\text{C}$, $V_{CC} = 5\text{V} \pm 10\%$)

Item	Symbol	23C1622-10		23C1622-12	
		MIN.	MAX.	MIN.	MAX.
Read Cycle Time	tRC	100ns	-	120ns	-
Address Access Time	tAA	-	100ns	-	120ns
Chip Enable Access Time	tACE	-	100ns	-	120ns
Page Mode Access Time	tPA	-	30ns	-	50ns
Output Enable Time	tOE	-	30ns	-	50ns
Output Hold After Address	tOH	0ns	-	0ns	-
Output High Z Delay	tHZ	-	20ns	-	20ns

Note: Output high-impedance delay (tHZ) is measured from $\overline{\text{OE}}$ or $\overline{\text{CE}}$ going high, and this parameter guaranteed by design over the full voltage and temperature operating range - not tested.

AC Test Conditions

Input Pulse Levels	0.4V~ 2.4V
Input Rise and Fall Times	10ns
Input Timing Level	1.5V
Output Timing Level	0.8V and 2.0V
Output Load	See Figure



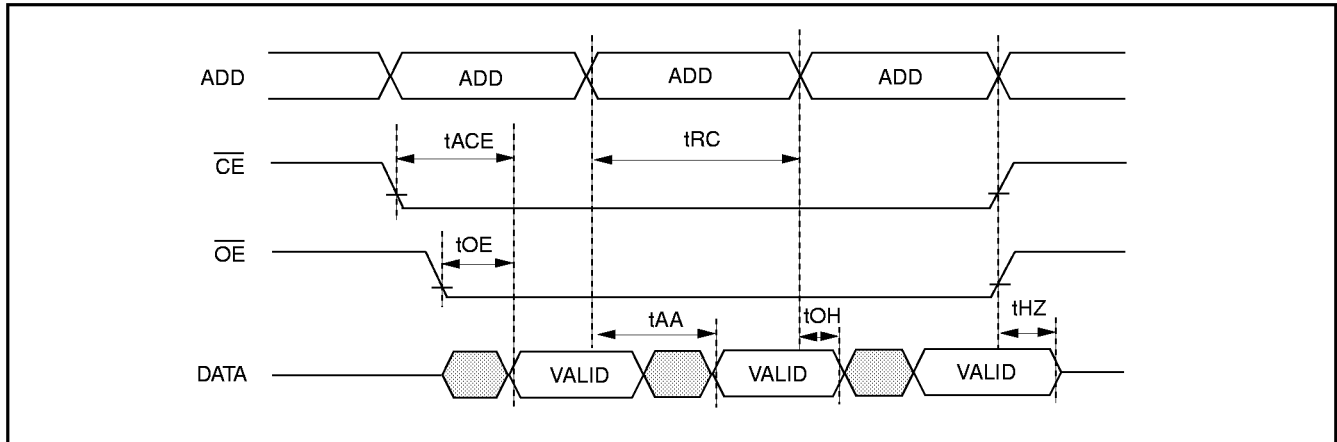
Note: No output loading is present in tester load board.

Active loading is used and under software programming control.

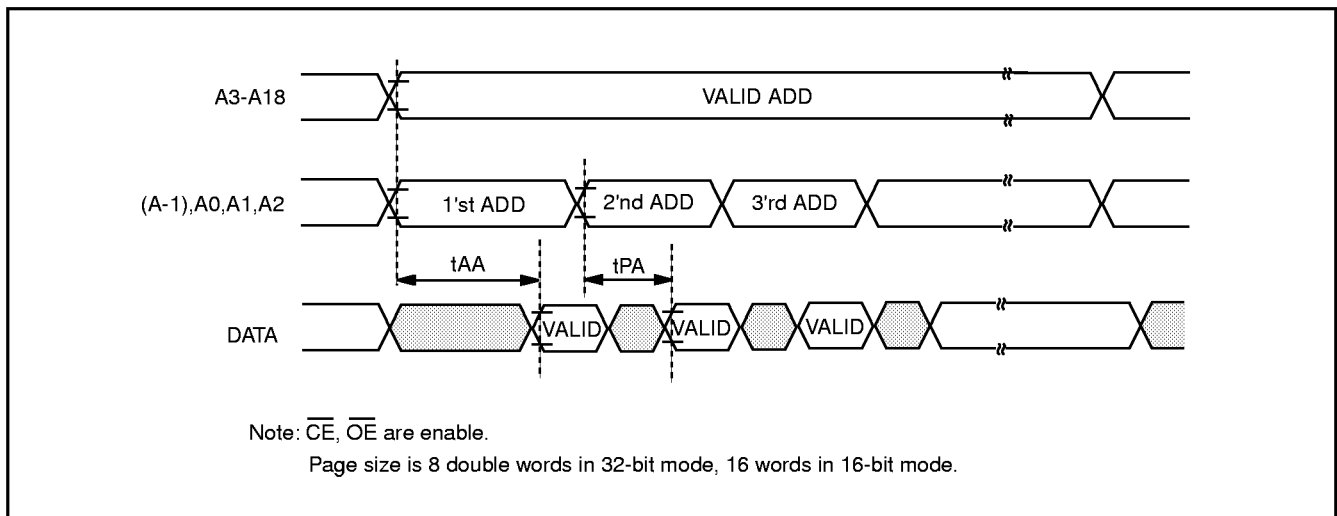
Output loading capacitance includes load board's and all stray capacitance.

TIMING DIAGRAM

RANDOM READ



PAGE READ



REVISION HISTORY

Revision	Description	Page	Date
1.4	Block Diagram: Added block diagram.		
1.5	Absolute Maximum Ratings: Added note describe the minimum and maximum overshoot raanges.		
1.6	AC Characteristics: Added 120ns grade item.	P3	MAY/25/1998
1.7	AC Characteristics: tOH 10ns --> 0ns	P3	FEB/01/1999